



**VOLTAGE RANGE: 40 - 200 V**

**CURRENT: 20 A**

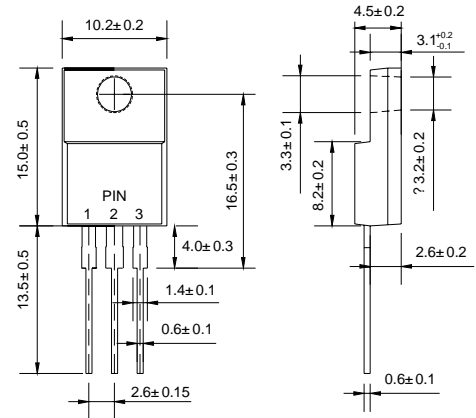
**ITO-220AB**

## Features

- ◇ High surge capacity.
- ◇ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- ◇ Metal silicon junction, majority carrier conduction.
- ◇ High current capacity, low forward voltage drop.
- ◇ Guard ring for over voltage protection.

## Mechanical Data

- ◇ Case: JEDEC ITO-220AB, molded plastic body
- ◇ Polarity: As marked
- ◇ Position: Any
- ◇ Weight: 0.06 ounce, 1.67 grams



Dimensions in millimeters

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

PARAMETER	SYMBOL	MBR 2040FCT	MBR 2045FCT	MBR 2050FCT	MBR 2060FCT	MBR 2080FCT	MBR 2090FCT	MBR 20100FCT	MBR 20150FCT	MBR 20200FCT	UNITS
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	40	45	50	60	80	90	100	150	200	V
Maximum RMS Voltage	$V_{RMS}$	28	31.5	35	42	56	63	70	105	140	V
Maximum DC Blocking Voltage	$V_{DC}$	40	45	50	60	80	90	100	150	200	V
Maximum Average Forward Current (See fig.1)	$I_{F(AV)}$	20									A
Peak Forward Surge Current :8.3ms single half sine-wave superimposed on rated load(JEDEC method)	$I_{FSM}$	150									A
Maximum Forward Voltage at 10A, per leg	$V_F$	0.7		0.8		0.85		0.92			V
Maximum DC Reverse Current $T_J=25^\circ\text{C}$ at Rated DC Blocking Voltage $T_J=125^\circ\text{C}$	$I_R$	0.05 20				0.02 20					mA
Typical Thermal Resistance	$R_{\theta JC}$	2									°C / W
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-50 to +150								-55 to +175	°C

## RATING AND CHARACTERISTIC CURVES

